

**25V NPN HIGH CURRENT TRANSISTOR IN SOT223**

**Features**

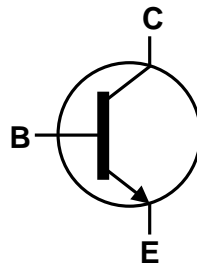
- $BV_{CEO} > 25V$
- $I_C = 7A$  High Continuous Collector Current
- $I_{CM} = 20A$  Peak Pulse Current
- Very Low Saturation Voltage  $V_{CE(SAT)} < 110mV @ 1A$
- $R_{CE(SAT)} = 36m\Omega$  at 5A for a Low Equivalent On-Resistance
- $h_{FE}$  Specified Up to 20A for a High Gain Hold Up
- $P_{TOT} = 3W$
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

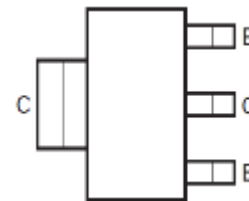
- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208<sup>(e3)</sup>
- Weight: 0.112 grams (Approximate)



Top View



Device Symbol



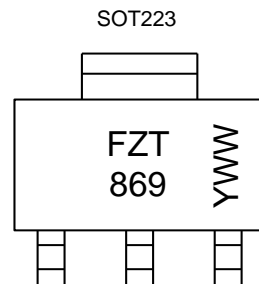
Top View  
Pin-Out

**Ordering Information** (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT869TA	AEC-Q101	FZT869	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**



FZT 869 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 7 = 2017)  
 WW or  $\bar{W}W$  = Week Code (01–53)

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Continuous Collector Current	I <sub>C</sub>	7	A
Peak Pulse Current	I <sub>CM</sub>	20	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

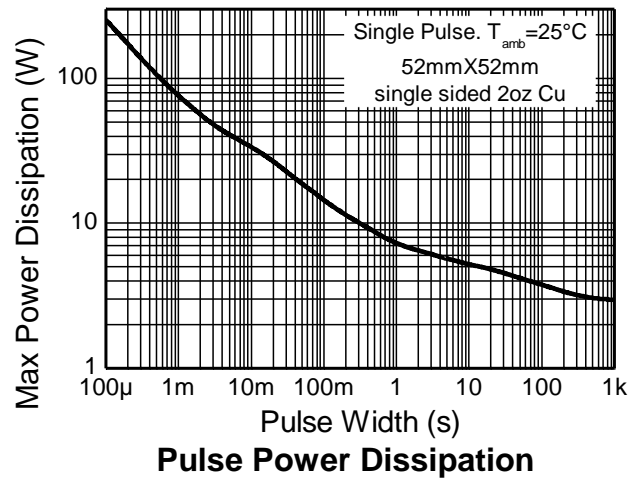
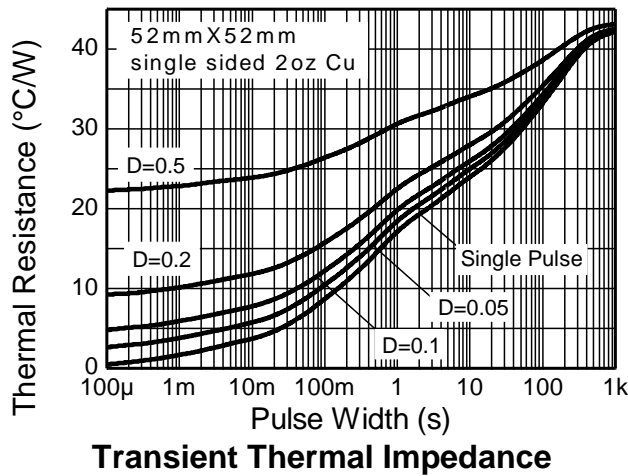
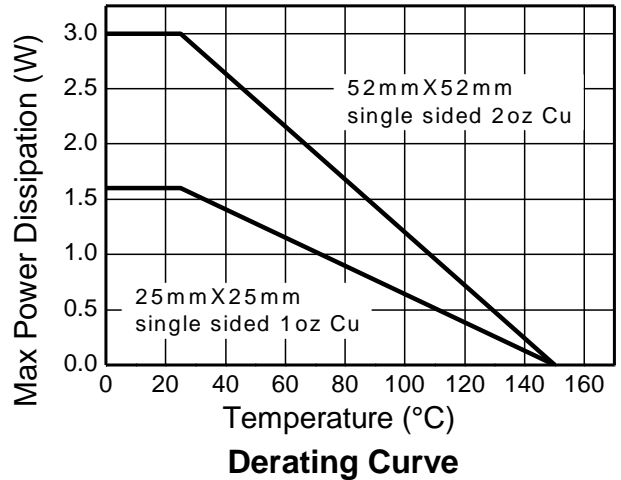
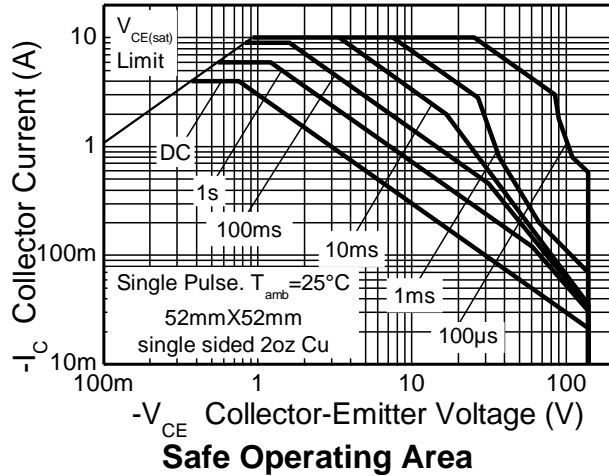
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P <sub>D</sub>	3	W
		24	
		1.6	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	12.8	°C/W
		42	
Thermal Resistance Junction to Lead	R <sub>θJA</sub>	78	°C/W
	R <sub>θJL</sub>	8.8	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
  - Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
  - Thermal resistance from junction to solder-point (at the end of the collector lead).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

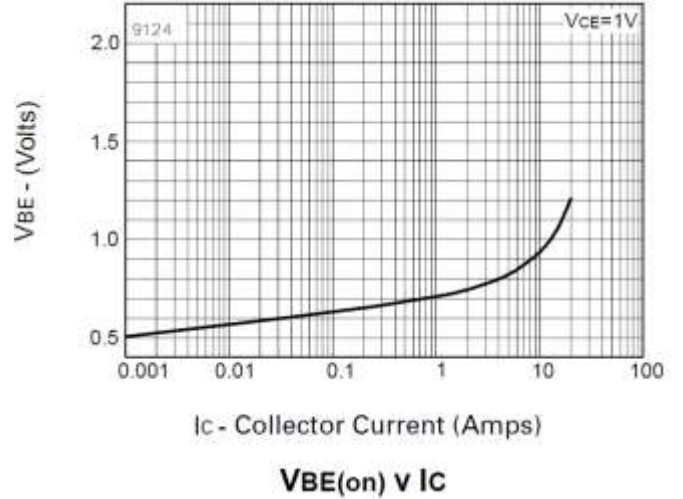
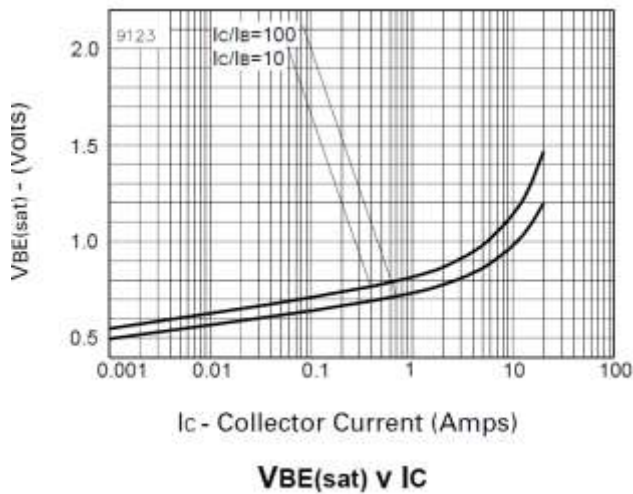
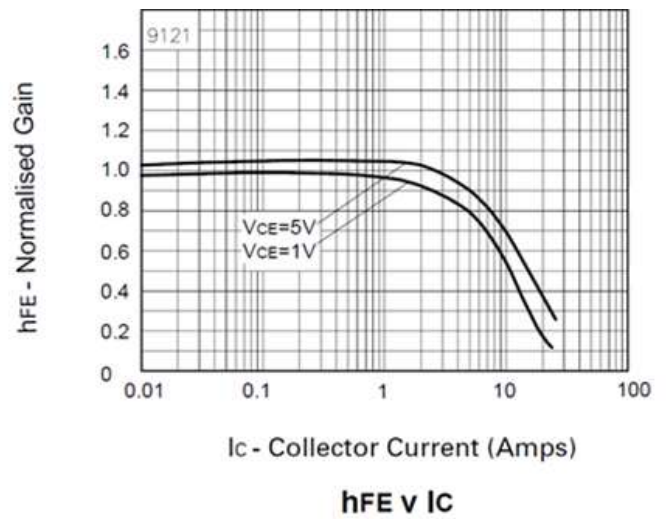
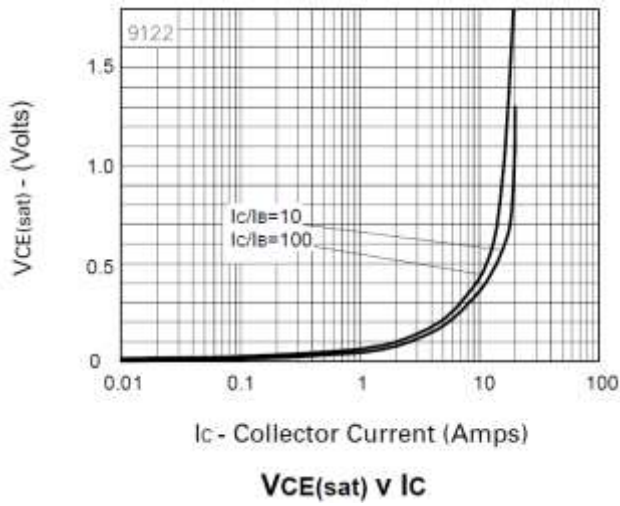


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	120	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CER</sub>	60	120	—	V	I <sub>C</sub> = 1μA, R <sub>B</sub> ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	25	35	—	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6	8	—	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	—	—	50 1	nA μA	V <sub>CB</sub> = 50V V <sub>CB</sub> = 50V, T <sub>A</sub> = +100°C
Collector Cut-off Current	I <sub>CER</sub>	—	—	50 1	nA μA	V <sub>CE</sub> = 50V, R <sub>B</sub> ≤ 1kΩ V <sub>CE</sub> = 50V, T <sub>A</sub> = +100°C
Emitter Cut-off Current	I <sub>EBO</sub>	—	—	10	nA	V <sub>EB</sub> = 6V
DC Current Gain (Note 9)	h <sub>FE</sub>	300	450	—	—	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 1V
		300	450	—		I <sub>C</sub> = 1A, V <sub>CE</sub> = 1V
		200	300	—		I <sub>C</sub> = 7A, V <sub>CE</sub> = 1V
		40	100	—		I <sub>C</sub> = 20A, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(SAT)</sub>	—	35	50	mV	I <sub>C</sub> = 0.5mA, I <sub>B</sub> = 10mA
		—	67	110		I <sub>C</sub> = 1A, I <sub>B</sub> = 10mA
		—	168	215		I <sub>C</sub> = 2A, I <sub>B</sub> = 10mA
		—	—	350		I <sub>C</sub> = 6.5A, I <sub>B</sub> = 150mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(SAT)</sub>	—	—	1.2	V	I <sub>C</sub> = 6.5A, I <sub>B</sub> = 300mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(ON)</sub>	—	—	1.13	mV	I <sub>C</sub> = 6.5A, V <sub>CE</sub> = 1V
Current Gain-Bandwidth Product (Note 9)	f <sub>T</sub>	—	100	—	MHz	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 10V, f = 50MHz
Output Capacitance	C <sub>OBO</sub>	—	70	—	pF	V <sub>CB</sub> = 10V, f = 1MHz
Switching Times	t <sub>ON</sub>	—	60	—	ns	I <sub>C</sub> = 1A, V <sub>CC</sub> = 10V, I <sub>B1</sub> = -I <sub>B2</sub> = 100mA
	t <sub>OFF</sub>	—	680	—		

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

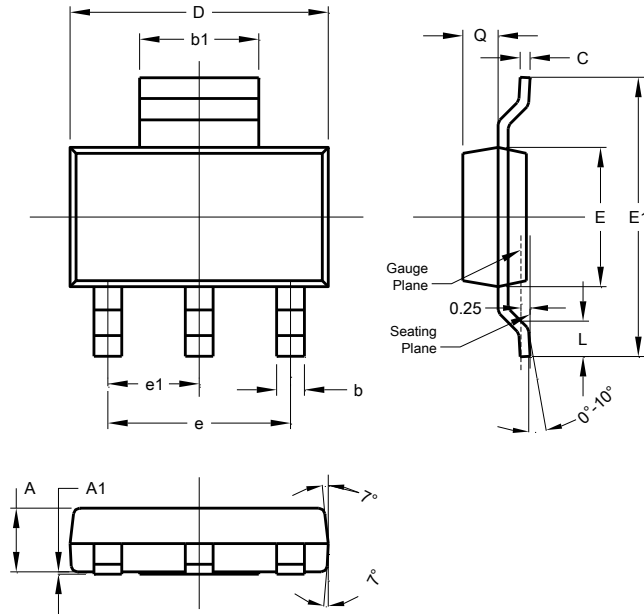
**Typical Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)



**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT223**

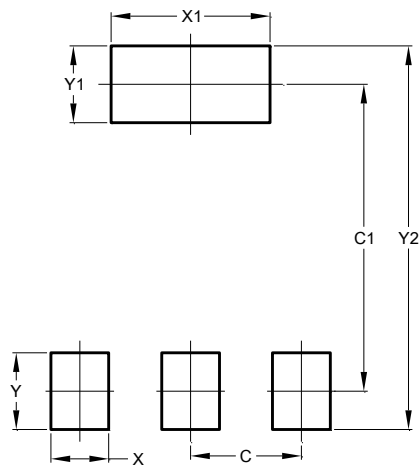


SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT223**



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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